


Substitute Form PTO-1449 (Modified)	U.S. Department of Commerce Patent and Trademark Office	Attorney's Docket No. <b>07977-218003</b>	Application No. <b>New Divisional Appln.</b>
<b>Information Disclosure Statement by Applicant</b> (Use several sheets if necessary) (37 CFR §1.98(b))		Applicant <b>Shunpei Yamazaki et al.</b>	
		Filing Date <b>January 9, 2004</b>	Group Art Unit <b>Unknown</b>



U.S. Patent Documents							
Examiner Initial	Desig. ID	Document Number	Publication Date	Patentee	Class	Subclass	Filing Date If Appropriate
	AA	5,170,244	12/08/92	Dohjo, et al.			
	AB	5,250,931	10/05/93	Misawa, et al.			
	AC	5,525,822	06/11/96	Vinal			
	AD	5,744,824	04/28/98	Kousai, et al.			
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	AQ	2001/0018224	08/30/01	Zhang			
	AR						


Foreign Patent Documents or Published Foreign Patent Applications								
Examiner Initial	Desig. ID	Document Number	Publication Date	Country or Patent Office	Class	Subclass	Translation	
							Yes	No
	AS	1118521	03/13/96	China			ABS	
	AT	JP 07-135318	05/23/95	Japan			ABS	
	AU	JP 08-078329	03/22/96	Japan			ABS	
	AV	JP 08 213634	08/20/96	Japan			ABS	
	AW	JP 08 288522	11/01/96	Japan			ABS	
	AX	JP 09-022077	01/20/97	Japan			Full	

Examiner Signature <b>J. MONDT</b>	Date Considered <b>03/25/05</b>
EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	

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Foreign Patent Documents or Published Foreign Patent Applications								
Examiner Initial	Desig. ID	Document Number	Publication Date	Country or Patent Office	Class	Subclass	Translation	
							Yes	No
	AY	JP 09-312260	12/02/97	Japan			ABS	
	AZ	JP 10-270363	10/09/98	Japan			ABS	

Other Documents (include Author, Title, Date, and Place of Publication)		
Examiner Initial	Desig. ID	Document
	BA	Kuznetsov, et al., "Silicide precipitate formation and solid phase regrowth of Ni+-implanted amorphous silicon", Inst. Phys. Conf. Ser. No. 134:Section 4, Paper presented at Microsc. Semicond. Mater. Conf., April 1993, pp. 191-194.
	BB	Kuznetsov, et al., "Transient kinetics in solid phase epitaxy of Ni doped amorphous silicon", Nuclear Instruments & Methods in Physics Research, B 96, 1995, pp. 261-264.
	BC	
	BD	

Examiner Signature <i>J. MONDT</i> 	Date Considered 03/25/05
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